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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Alexei A. Erchak  
Serial No. : 10/724,029  
Filed : November 26, 2003  
Title : HIGH-EFFICIENCY LIGHT-EMITTING DEVICES

Art Unit : 2879  
Examiner : Martin R. Hodge

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Applicant submits the references listed on the attached form PTO-1449.

This statement is being filed after a first Office action on the merits, but before receipt of a final Office action or a Notice of Allowance. A check for \$180 in payment of the late submission fee of §1.17(p) is enclosed. Please apply any other charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: 8/11/04

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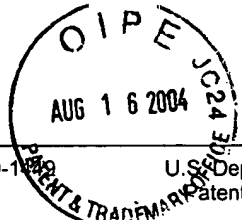
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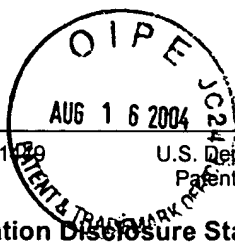
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| Substitute Form PTO-1449<br>(Modified)<br><br><b>Information Disclosure Statement<br/>by Applicant</b><br>(Use several sheets if necessary)<br><br>(37 CFR §1.98(b)) | U.S. Department of Commerce<br>Patent and Trademark Office | Attorney's Docket No.<br><b>16459-010001</b> | Application No.<br><b>10/724,029</b> |
|  | Applicant<br><b>Alexei A. Erchak</b>                       |  |                                      |
|  | Filing Date<br><b>November 26, 2003</b>                    | Group Art Unit<br><b>2879</b>                |                                      |

| U.S. Patent Documents |           |                 |                  |                     |       |          |                            |
|-----------------------|-----------|-----------------|------------------|---------------------|-------|----------|----------------------------|
| Examiner Initial      | Desig. ID | Document Number | Publication Date | Patentee            | Class | Subclass | Filing Date If Appropriate |
|                       | AA        | 5,359,345       | 10/25/94         | Hunter et al.       |       |          |                            |
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| Foreign Patent Documents or Published Foreign Patent Applications |           |                 |                  |                          |       |          |             |    |
|---|-----------|-----------------|------------------|--------------------------|-------|----------|-------------|----|
| Examiner Initial  | Desig. ID | Document Number | Publication Date | Country or Patent Office | Class | Subclass | Translation |    |
|   |           |                 |                  |                          |       |          | Yes         | No |
|   | AL        | WO 98/14986     | 04/09/98         | PCT                      |       |          |             |    |
|   | AM        |                 |                  |                          |       |          |             |    |

| Other Documents (include Author, Title, Date, and Place of Publication) |           |  |
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| Examiner Initial  | Desig. ID | Document   |
|   | AN        | W.S. Wong et al. "Damage-free separation of GaN thin films from sapphire substrates", Appl. Phys. Lett. 72 (5), February 2, 1998, pages 599-601  |
|   | AO        | M.K. Kelly et al. "Optical process for liftoff of Group III-nitride films", Physica Status Solidi; Rapid Research Note, November 28, 1996, 2 pages.  |
|   | AP        | A. A. Erchak et al. "Enhanced coupling to vertical radiation using a two-dimensional photonic crystal in a semiconductor light-emitting diode", Appl. Phys. Lett. (78 (5), January 29, 2001, pages 563-565 |
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| Examiner Signature   | Date Considered |
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| Substitute Form PTO-1029<br>(Modified)<br><br><b>Information Disclosure Statement<br/>by Applicant</b><br>(Use several sheets if necessary)<br><br>(37 CFR §1.98(b)) | U.S. Department of Commerce<br>Patent and Trademark Office | Attorney's Docket No.<br><b>16459-010001</b> | Application No.<br><b>10/724,029</b> |
|  | Applicant<br><b>Alexei A. Erchak</b>                       |  |                                      |
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| Other Documents (include Author, Title, Date, and Place of Publication) |           |  |
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| Examiner Initial  | Desig. ID | Document   |
|   | AT        | M. Krames et al "Introduction to the Issue on High-Efficiency Light-Emitting Diodes", IEEE Journal on selected topic in quantum electronics, Vol. 8, No. 2 March/April 2002, pages 185-188                 |
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|   | AFF       | T. N. Oder et al. "III-nitride photonic crystals", Appl. Phys. Lett. 83 (6), August 11, 2003, pages 1231-1233  |
|   | AGG       | M.K. Kelly et al. "Optical patterning of GaN films", Appl. Phys. Lett 68 (12), September 16, 1996, pages 1749-1751   |

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